



Vishay Semiconductors

# Ultralow V<sub>F</sub> Ultrafast Rectifier, 6 A FRED Pt®

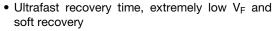




D-PAK (TO-252AA)

PRODUCT SUMMARY						
D-PAK (TO-252AA)						
6 A						
600 V						
1.25 V						
59 ns						
175 °C						
Single die						

#### **FEATURES**





• For PFC DCM operation

· Low leakage current

Compliant to RoHS Directive 2002/95/EC

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

• Halogen-free according to IEC 61249-2-21 definition







FREE

#### **DESCRIPTION/APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Peak repetitive reverse voltage	$V_{RRM}$		600	V					
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 156 °C	6						
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	80	Α					
Peak repetitive forward current	I <sub>FM</sub>	T <sub>C</sub> = 156 °C, f = 20 kHz, d = 50 %	12						
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C					

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-					
Forward valtage	V	I <sub>F</sub> = 6 A	-	0.99	1.25	V				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C	-	0.87	1.05					
Deverse leakage august	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	5					
Reverse leakage current		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	125	μA				
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	=	3.5	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH				

# VS-6EWL06FN-M3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
Reverse recovery time		$I_F = 1 A, dI_F/dt = 10$	$00 \text{ A/}\mu\text{s}, \text{ V}_{\text{R}} = 30 \text{ V}$	-	59	70				
	t <sub>rr</sub>	$I_F = 1 A, dI_F/dt = 50$	-	75	-	ns				
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 6A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	154	-	- A			
		T <sub>J</sub> = 125 °C		-	215	-				
Dools rooms ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	13.3	-				
Peak recovery current		T <sub>J</sub> = 125 °C		-	15.4	-				
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	1055	-	»C			
	$Q_{rr}$	T <sub>J</sub> = 125 °C		-	1600	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C			
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	3	°C/W			
Approximate weight				0.3		g			
Approximate weight				0.01		OZ.			
Marking device		Case style D-PAK (TO-252AA)	6EWL06FN						





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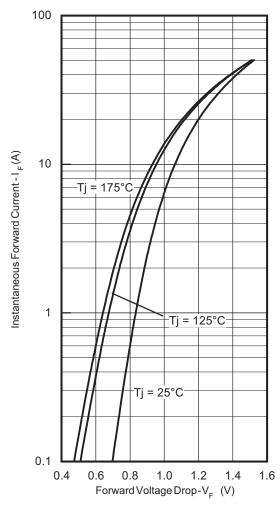


Fig. 1 - Typical Forward Voltage Drop Characteristics

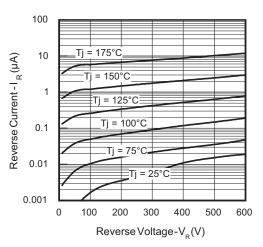


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

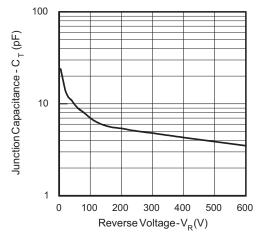


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

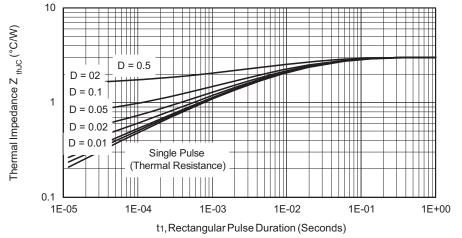


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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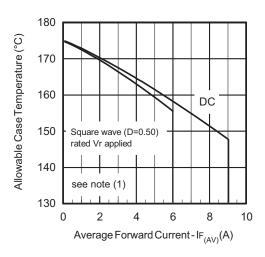


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

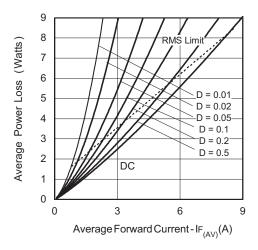


Fig. 6 - Forward Power Loss Characteristics

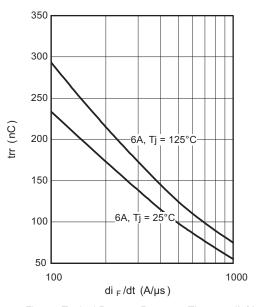


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

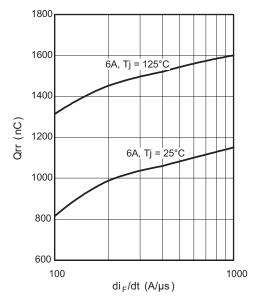


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd<sub>REV</sub> = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$ 



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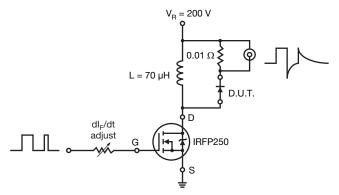
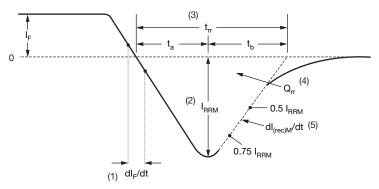


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (4)  $\rm Q_{rr}$  area under curve defined by  $\rm t_{rr}$  and  $\rm I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

### VS-6EWL06FN-M3

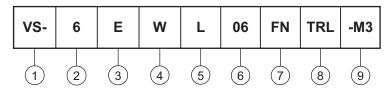
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#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Current rating (6 = 6 A)
- Circuit configuration:
  - E = Single diode
- Package identifier:
  - W = D-PAK
- 5 L = Low V<sub>F</sub>, fast recovery
- 6 Voltage rating (06 = 600 V)
- 7 FN = TO-252AA
- 8 • None = Tube
  - TR = Tape and reel
  - TRL = Tape and reel (left oriented)
  - TRR = Tape and reel (right oriented)
- 9 Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-6EWL06FN-M3	75	3000	Antistatic plastic tube						
VS-6EWL06FNTR-M3	2000	2000	13" diameter reel						
VS-6EWL06FNTRL-M3	3000	3000	13" diameter reel						
VS-6EWL06FNTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95176					
SPICE model	www.vishay.com/doc?95218					



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**NOTES** 

3

2

MAX.

0.410

0.070

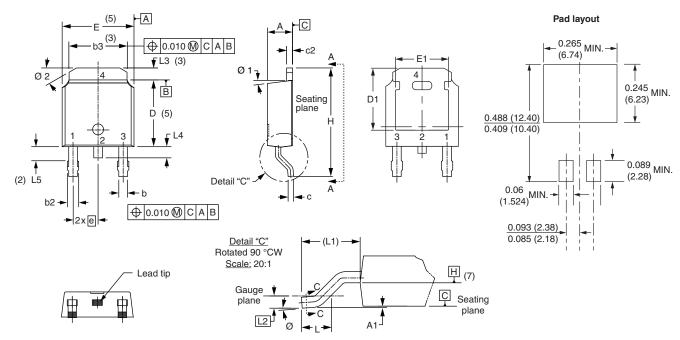
0.050

0.040

0.060

# **D-PAK (TO-252AA)**

#### **DIMENSIONS** in millimeters and inches



Ī	SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		
		MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	2.29 BSC		BSC
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.
ſ	b3	4.95	5.46	0.195	0.215	3	3 L2 0.51 BSC		0.020	BSC		
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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